



KC-6125
B. E. II (Sem. III) (CHE) Examination
November/December – 2012
Basic Electronics

Time : 3 Hours]

[Total Marks : 100

Instructions :

(1)

<p>नीचे दृष्टावेव निशानीवाणी विगतो उत्तरवडी पर अवश्य वपनी. Fillup strictly the details of signs on your answer book.</p> <p>Name of the Examination : B. E. II (Sem. III) (CHE)</p> <p>Name of the Subject : Basic Electronics</p> <p>Subject Code No. : 6 1 2 5 Section No. (1, 2,.....): Nil</p>	<p>Seat No. : <input type="text"/><input type="text"/><input type="text"/><input type="text"/><input type="text"/><input type="text"/></p> <div style="border: 1px solid black; border-radius: 15px; padding: 10px; text-align: center; width: 100%;">Student's Signature</div>
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- (2) Attempt all questions.
- (3) Figures to the right indicates full marks.
- (4) Assume suitable data wherever necessary.

- 1 (a) Answers of the following : 10
 - (i) A PN junction acts as a _____ (unidirectional, bidirectional)
 - (ii) The ripple factor of a half rectifier is _____.
(0.48, 2, 1.21, 2,5)
 - (iii) Find the value of β if $\alpha = 0.99$.
 - (iv) Define negative feedback.
 - (v) Relation between α and β is _____.
 - (vi) Full form of UJT is _____.
 - (vii) $I_C = \beta I_B +$ _____
 - (viii) When pure semiconductor heated, its resistance _____. (goes up, goes down, remain constant)
 - (ix) In breakdown region, a zener diode behaves like a _____ source. (constant current, constant voltage)
 - (x) Define Transistor Biasing.
- (b) Derive the relation between α and β for common emitter connection. 4
- (c) Transistor load line analysis in CE configuration. 6

- 2 (a) What is filter ? Explain π filter with circuit diagram, input and output waveform. 7
 (b) Explain push pull amplifier with circuit diagram and its operation. 8

OR

- 2 (a) Explain Full wave bridge rectifier with its circuit diagram, operation, advantages and disadvantages. 10
 (b) Class B power amplifier in detail. 5

- 3 Explain any three : 15
 (i) Half wave rectifier with circuit diagram.
 (ii) UJT characteristic with diagram.
 (iii) V-I characteristic of diode
 (iv) Class A power amplifier
 (v) Zener diode

- 4 (a) Answer the following : 10
 (i) Define Holding current.
 (ii) Define latching current.
 (iii) Explain Barkhausen criteria.
 (iv) How does SCR differ from ordinary rectifier ?
 (v) Explain the difference between Diac and Triac.
 (b) Draw and explain the operation and the V-I Characteristic of Triac. 10

- 5 (a) Draw and explain the V-I characteristic of SCR. 8
 (b) Explain the working of CRT with neat diagram. 7

OR

- 5 (a) What do you mean by thermionic emission ? Explain Richardson-Dushondu equation. 8
 (b) Explain Hartley oscillator with neat diagram. 7

- 6 Write short note on any three : 15
 (i) SCR
 (ii) Application of UJT
 (iii) Multimeter
 (iv) Diac
 (v) Photo Conductive cell.